#### Product Preview

# Low-Voltage CMOS 16-Bit Buffer

## With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX16244 is a high performance, non–inverting 16–bit buffer operating from a 2.7 to 3.6V supply. The device is nibble controlled. Each nibble has separate Output Enable inputs which can be tied together for full 16–bit operation. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V<sub>I</sub> specification of 5.5V allows MC74LCX16244 inputs to be safely driven from 5V devices. The MC74LCX16244 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

 $\underline{\text{Cu}}$ rrent drive capability is 24mA at the outputs. The Output Enable (OEn) inputs, when HIGH, disable the outputs by placing them in a HIGH Z condition.

- Designed for 2.7 to 3.6V V<sub>CC</sub> Operation
- 5V Tolerant Interface Capability With 5V TTL Logic
- · Supports Live Insertion and Withdrawal
- IOFF Specification Guarantees High Impedance When V<sub>CC</sub> = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

The MC74LCX16244 contains sixteen non–inverting buffers with 3–state 5V–tolerant outputs. The device is nibble controlled with each nibble functioning identically, but independently. The control pins may be tied together to obtain full 16–<u>bit operation</u>. The 3–state outputs are controlled by an Output Enable (<u>OEn</u>) input for each nibble. When OEn is LOW, the outputs are on. When OEn is HIGH, the outputs are in the high impedance state.

#### MC74LCX16244



LOW-VOLTAGE CMOS 16-BIT BUFFER



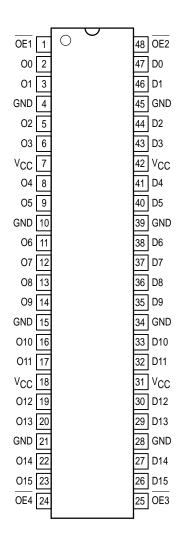
**DT SUFFIX**PLASTIC TSSOP PACKAGE
CASE 1201–01

#### **PIN NAMES**

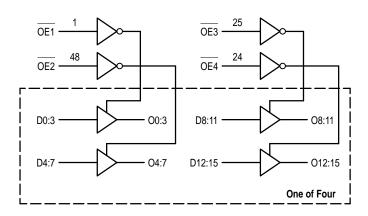
Pins	Function				
OEn D0-D15 O0-O15	Output Enable Inputs Inputs Outputs				

This document contains information on a product under development. Motorola reserves the right to change or discontinue this product without notice.





#### **LOGIC DIAGRAM**



OE1	D0:3	O0:3	OE2	D4:7	04:7	OE3	D8:11	O8:11	OE4	D12:15	O12:15
L	L	Н	L	L	Н	L	L	Н	L	L	Н
L	Н	L	L	Н	L	L	Н	L	L	Н	L
Н	Х	Z	Н	Х	Z	Н	Х	Z	Н	Х	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions Are Acceptable, for I<sub>CC</sub> reasons, DO NOT FLOAT Inputs

#### **ABSOLUTE MAXIMUM RATINGS\***

Symbol	Parameter	Value	Condition	Unit
VCC	DC Supply Voltage	-0.5 to +7.0		٧
VI	DC Input Voltage	$-0.5 \le V_{I} \le +7.0$		V
Vo	DC Output Voltage	$-0.5 \le V_{O} \le +7.0$	Output in 3-State	V
		$-0.5 \le V_O \le V_{CC} + 0.5$ 1	Output in HIGH or LOW State	V
Ικ	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA
lok	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA
		+50	VO > VCC	mA
lo	DC Output Source/Sink Current	±50		mA
Icc	DC Supply Current Per Supply Pin	±100		mA
IGND	DC Ground Current Per Ground Pin	±100		mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150		°C

Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied.

1. I<sub>O</sub> absolute maximum rating must be observed.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Тур	Max	Unit
Vcc	Supply Voltage Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
VI	Input Voltage	0		5.5	V
Vo	Output Voltage (HIGH or LOW State) (3–State)	0 0		VCC 5.5	V
loн	HIGH Level Output Current, V <sub>CC</sub> = 3.0V – 3.6V			-24	mA
lol	LOW Level Output Current, V <sub>CC</sub> = 3.0V – 3.6V			24	mA
<sup>I</sup> ОН	HIGH Level Output Current, V <sub>CC</sub> = 2.7V - 3.0V			-12	mA
loL	LOW Level Output Current, V <sub>CC</sub> = 2.7V – 3.0V			12	mA
TA	Operating Free–Air Temperature	-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, $V_{IN}$ from 0.8V to 2.0V, $V_{CC} = 3.0V$	0		10	ns/V

#### DC ELECTRICAL CHARACTERISTICS

			T <sub>A</sub> = -40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input Voltage (Note 1)	2.7V ≤ V <sub>CC</sub> ≤ 3.6V	2.0		V
V <sub>IL</sub>	LOW Level Input Voltage (Note 1)	$2.7V \le V_{CC} \le 3.6V$		0.8	V
Vон	HIGH Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$ ; $I_{OH} = -100\mu A$	V <sub>CC</sub> – 0.2		V
		$V_{CC} = 2.7V; I_{OH} = -12mA$	2.2		
		$V_{CC} = 3.0V; I_{OH} = -18mA$	2.4		
		$V_{CC} = 3.0V; I_{OH} = -24mA$	2.2		
VOL	LOW Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$ ; $I_{OL} = 100\mu A$		0.2	٧
		$V_{CC} = 2.7V; I_{OL} = 12mA$		0.4	]
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 16mA		0.4	]
		$V_{CC} = 3.0V; I_{OL} = 24mA$		0.55	

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<sup>1.</sup> These values of  $V_I$  are used to test DC electrical characteristics only. Functional test should use  $V_{IH} \ge 2.4 V$ ,  $V_{IL} \le 0.5 V$ .

#### DC ELECTRICAL CHARACTERISTICS (continued)

			T <sub>A</sub> = -40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
lį	Input Leakage Current	$2.7V \le V_{CC} \le 3.6V; \ 0V \le V_{I} \le 5.5V$		±5.0	μΑ
loz	3-State Output Current	$2.7 \le V_{CC} \le 3.6V$ ; $0V \le V_{O} \le 5.5V$ ; $V_{I} = V_{IH}$ or $V_{IL}$		±5.0	μΑ
loff	Power-Off Leakage Current	$V_{CC} = 0V$ ; $V_I$ or $V_O = 5.5V$		10	μΑ
Icc	Quiescent Supply Current	$2.7 \le V_{CC} \le 3.6V$ ; $V_I = GND$ or $V_{CC}$		20	μΑ
		$2.7 \le V_{CC} \le 3.6V$ ; $3.6 \le V_I$ or $V_O \le 5.5V$		±20	μΑ
ΔlCC	Increase in I <sub>CC</sub> per Input	$2.7 \le V_{CC} \le 3.6V; V_{IH} = V_{CC} - 0.6V$		500	μΑ

#### AC CHARACTERISTICS<sup>1</sup> ( $t_R = t_F = 2.5 \text{ns}$ ; $C_L = 50 \text{pF}$ ; $R_L = 500 \Omega$ )

			Limits			
			Тд	= -40°C to +	-85°C	
			V <sub>CC</sub> = 3.0	V to 3.6V	V <sub>CC</sub> = 2.7V	
Symbol	Parameter	Waveform	Min	Max	Max	Unit
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation Delay Input to Output	1	1.5 1.5	4.5 4.5	5.2 5.2	ns
<sup>t</sup> PZH <sup>t</sup> PZL	Output Enable Time to High and Low Level	2	1.5 1.5	5.5 5.5	6.3 6.3	ns
<sup>t</sup> PHZ <sup>t</sup> PLZ	Output Disable Time From High and Low Level	2	1.5 1.5	5.4 5.4	5.7 5.7	ns
<sup>t</sup> OSHL <sup>t</sup> OSLH	Output-to-Output Skew (Note 2)			1.0 1.0		ns

<sup>1.</sup> These AC parameters are preliminary and may be modified prior to release.

#### **DYNAMIC SWITCHING CHARACTERISTICS**

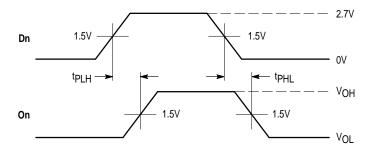
			T <sub>A</sub> = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
VOLP	Dynamic LOW Peak Voltage <sup>1</sup>	$V_{CC} = 3.3V$ , $C_L = 50pF$ , $V_{IH} = 3.3V$ , $V_{IL} = 0V$		0.8		V
V <sub>OLV</sub>	Dynamic LOW Valley Voltage <sup>1</sup>	$V_{CC} = 3.3V$ , $C_L = 50pF$ , $V_{IH} = 3.3V$ , $V_{IL} = 0V$		0.8		V

<sup>1.</sup> Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

#### **CAPACITIVE CHARACTERISTICS**

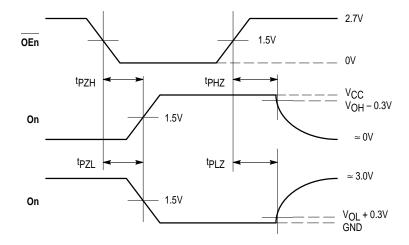
Symbol	Parameter	Condition	Typical	Unit
C <sub>PD</sub>	Power Dissipation Capacitance	10MHz, $V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	20	pF
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	7	pF
COUT	Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF

Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device.
 The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.



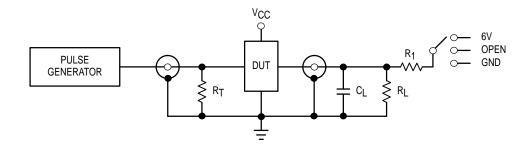
#### WAVEFORM 1 - PROPAGATION DELAYS

 $t_R$  =  $t_F$  = 2.5ns, 10% to 90%; f = 1MHz;  $t_W$  = 500ns



### $\label{eq:waveform 2-output enable and disable times} $$t_R = t_F = 2.5 ns, 10\% to 90\%; f = 1MHz; t_W = 500 ns$

Figure 1. AC Waveforms



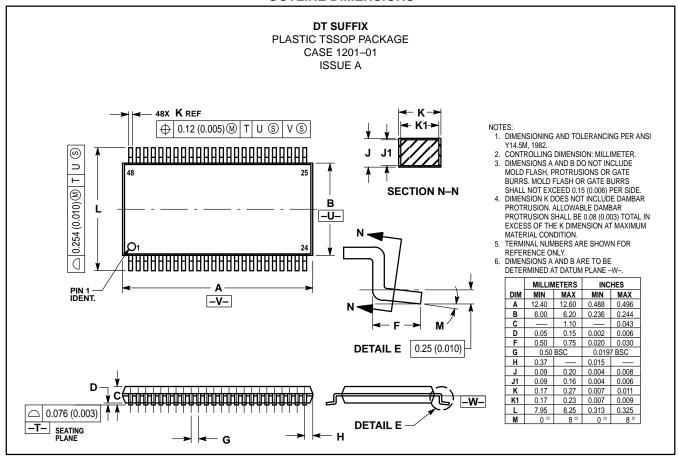
TEST	SWITCH
tPLH, tPHL	Open
tPZL, tPLZ	6V
Open Collector/Drain tpLH and tpHL	6V
<sup>t</sup> PZH <sup>, t</sup> PHZ	GND

 $C_L$  = 50pF or equivalent (Includes jig and probe capacitance)  $R_L$  =  $R_1$  = 500 $\Omega$  or equivalent  $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )

Figure 2. Test Circuit

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#### **OUTLINE DIMENSIONS**



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